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### **Improving Light Output and Coincidence Time Pesolution of** 1 Scintillating Crystals Using Nanoimprinted Photon.c Crystal Slabs 2

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### Abstract

14 Scintillating crystals are used in numerous applications on ionizing radiation detectors. In time of flight positron 15 emission tomography (TOF-PET) for example, both energy- an.' coincidence time resolution (CTR) are important characteristics that could significantly benefit if more h, ht i ver scintillators, otherwise trapped, could be collected 16 17 by the photodetector. A novel and promising method t extract more efficiently the light produced in crystal 18 scintillators with high index of refraction is to introd. A the nanopatterned photonic layer on the readout surface. 19 In this paper, we describe the patterning process of a pho-onic crystal layer made of TiO<sub>2</sub> with 390 nm diameter 20 21 10x10x10 mm<sup>3</sup> LYSO cube. The production process sed was nanoimprint lithography. A substantial increase in 22 light yield of  $\geq$  50% has been measured in good agreement with our simulations. An interesting result from these 23 measurements is that the improvement in 'ght o tput is independent of whether the crystal is read out from its 24 photonically patterned side or from the on, opposite to it. For all cases studied, the energy resolution improved by a 25 factor of 1.1. On the other hand, the CTC, being very threshold dependent, is unlike the light yield not subject to a 26 constant improvement. It turns out that at J w thresholds, the gain (improvement) in CTR is limited to 1.2, and then 27 rapidly increases to a value of more than? at h' gher thresholds. This is mainly explained by an additionally induced 28 light transfer time spread of the pb /tonic p. '.ern. Several configurations with and without Teflon wrapping were 29 investigated.

30 Keywords: Scintillators; Photon<sup>in</sup> crystals, Coincidence Time Resolution; Light yield; Nanoimprint Lithography; 31 **Fast Timing Detector** 

#### 1. Introduction 32

33 Scintillating crystals . ~ wid y used for the detection of ionizing particles in various applications, e.g. in 34 high energy physics ca<sup>1</sup> ... imetry, medical detectors, and homeland security.

35 An important characteric ic of scintillators is their energy resolution. In positron emission tomography (PET) applications. w. are scintillators are used to detect two 511 keV gammas from electron-positron 36 annihilation, the nergy resolution enables to filter out scattered and other background events having energies 37 38 other than the 51 keV p lotoelectric events. High energy resolution ( $E_{res}$ ) increases the signal to noise ratio and 39 hence the detector sectorized vity. The statistical contribution to the energy resolution  $E_{res}$  depends on the collected 40 light in the for two tay:

$$E_{res} \propto \frac{1}{\sqrt{LY_{coll}}}$$

41 where  $LY_{coll}$  denotes the measured light yield.

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Furthermore, for time-of-flight PET (TOF-PET) systems the coincidence time resolution (CTR) also plays an important role. High CTR is sought to reduce noise hits along the line of resonance and thereby further improve the signal to noise-ratio. Similar to energy resolution, the CTR depends on the measured light yield (LY):

$$CTR \propto \frac{1}{\sqrt{LY_{coll}}}$$

Therefore, both the energy resolution and the CTR can be improved if ... are light is collected by the photodetector. One suitable way in this direction, e.g., is to select specific stirtulators with a high intrinsic light yield or to wrap the scintillator with reflectors or diffusing materials stick as vikuiti [1] or Teflon. Also using optical coupling between the scintillator and photodetector helps mproved glight collection significantly. Nonetheless, using as an example a  $2x2x20 \text{ mm}^3$  LYSO crystal wrappe <sup>1</sup> with Feflon and mounted onto a PMT with optical coupling grease with index of refraction of 1.42 only 50% of the light produced in the crystal is extracted [2][3].

53 For specific applications, like PET and high energy calor. etry, scintillators are required to have high 54 density so as to absorb a maximum of energy of the traversing ionizin particles. This generally results in a high 55 refractive index (n=1.82 for LYSO) making light extraction from such scintillators difficult. If the medium, e.g. 56 air, between the photodetector and the crystal has a lower refractive index, the interface between them will cause 57 a significant amount of light to be trapped inside the cry tal. Furthermore, the entry windows of photodetectors have a typical refractive index of the order of n=1.5. This  $a_{5}$  ravates the mismatch in the involved indices even 58 when applying an optical coupling between the scintil we and the photodetector. Therefore, there will always be 59 a critical angle  $\theta_c$  that defines an extraction cone wh r, every light outside of this cone will be internally 60 61 reflected at the interface of the materials with different refr. stive indices.

A promising means to extract part of the (other, ise lost) light from outside of the extraction cone is to introduce a photonic crystal slab onto the reado.  $\pm$  surface of the scintillator. A photonic crystal slab is a thin layer of dielectric material imprinted on the scintillato, with a periodic nanostructure where the periodicity is of the order of the wavelength of the light. If  $\pm$  is tructure is properly designed, it has the potential to significantly enhance light extraction through the diffraction or light impinging on the crystal's readout surface. In this way, light from higher than 0<sup>th</sup> order diffraction medes can be extracted beyond the extraction cone [4][5].

# 68 2. Produced Sample

We have designed and produced a photonic crystal layer on the readout surface of a 10x10x10 mm<sup>3</sup> 69 LYSO:Ce cube to increase the amount of light to be extracted from this crystal. The cube used in this study was 70 produced by Crystal Photonic In. (CPI), with all six faces polished. On the bulk crystal, a TiO<sub>2</sub> laver was 71 imprinted with a nanopattern v S LSEF and NAPA Technologies [6], using nanoimprint lithography as shown 72 73 in Fig. 1. TiO<sub>2</sub> has a refractive  $m_1$ 'ex as high as 2.4 and is transparent to light emitted by LYSO: Ce at 420 nm. These are the two imports at features of any candidate material for photonic crystals [5]. The production method 74 75 used for our slab is described in detail by the following six steps (see also Fig. 1:) [insert figure 1 here, file 76 "NIL.tif"]

- First, a 300 nm la ver of 1 O<sub>2</sub> is sputtered on one of the surfaces, usually denoted as the exit window of the crystal. Thereafter a logar of aluminum (Al) is deposited on the TiO<sub>2</sub> coat, and then a resist applied on top of these (step 1 n Fig ).
- This is the laper or p which the desired pattern will then be imprinted via the nanoimprint lithographic process; i is a unique method where the pattern is imprinted into the resist layer with a so-called stamp (step 2 of Fig. 1, r plicated from a master mold. The master mold itself is produced beforehand using electron beam lithogra, hy.
- After having imprinted the resist, the pattern is transferred to the aluminum layer via wet-etching (**step 3**) where the aluminum only serves as a hard mask for the dry-etching of the TiO<sub>2</sub> (**step 5**), which will then produce the final, patterned layer on the scintillator (**step 6**). For our sample the chosen pattern consists of pillars arranged in a square lattice on top of the scintillator, as illustrated in Fig. 2a.

After the production of the photonic crystal on the bulk LYSO scintillator, the crystal is first visually inspected to assess how much of the surface is covered with the pattern, and to check for inhomogeneities visible by eye. Due to diffraction, the photonic crystal layer exhibits an iridescent shine on the cointillator surface, as seen in Fig. 2b. [insert figure 2a,b here, files "sketch\_pattern.tif" and "pic-surface.tac]

To examine the fabricated pattern on the scintillator more closely, the photon's crystal slab was visualized with a scanning electron microscope (SEM). Since the sample is nonconductive and hence subject to electrostatic charging during the imaging process the resulting images are not perfectly sharp. By imaging the sample from the top, the periodicity and diameter of the pattern could be valuated, but also possible defects in the shape of the structures and inhomogeneities in the pattern spotted. When the crystal is tilted one can also estimate the thickness of the nanostructure close to the edges of the crystal.

Figures <u>3a</u> and <u>3b</u> show SEM images recorded of the sample, all seen from top-down. The pattern shows regular periodicity and exhibits almost no defects. The diameter of <u>\*</u>... pinces on the pattern was measured to be 390 nm and the periodicity of the pattern to be 580 nm.

Fig. <u>3c</u> gives an image of the sample when tilted by 70 d orees A ter inspection of multiple images, we come to an average pillar height of 180 nm. Since the original  $TiO_2$ , ver was 300 nm thick this would then give rise to the assumption that the  $TiO_2$  layer between the pillars was not entirely etched away, i.e. all the way down to the bare scintillator surface. This could have been caused by two short an exposure time during the etching process (step 4 in Fig. <u>1</u>), therefore possibly leaving a residual <u>100</u> layer of ~120 nm. [insert figure 3.a,b,c here, files "SEM1.tif", "SEM2.tif" and "SEM3.tif"]

# 107 **3. Simulations**

### 108 **3.1 Simulation framework**

A simulation framework was set up to relief the increase in the amount of light extracted from the scintillator with a photonic crystal slab on the scind lator's readout surface compared to a bare scintillator. This scheme consists of Geant4 simulating the macroscopic part of our system, and CAMFR modeling the nanopatterned photonic crystal slab. Geant4 is a free toolkit for the simulation of the passage of particles through matter [7]. CAMFR is a so-called "Maxwe" solve ', based on eigenmode expansion [5][8].

With Geant4 we simulate the light products n in the LYSO cube due to radiation being converted inside the crystal and determine the trajectorie of the produced scintillation photons in the cube, potentially including reflective wrapping. The LYSO cube is in produced with a surface roughness of  $\sigma_{\alpha} = 1.7^{\circ}$ , where the meaning of  $\sigma_{\alpha}$  is described in [9], except for the edges [3] [10] simulated with a different  $\sigma_{\alpha}$  of 57°. From this Geant4 simulation we extract the angular distribution of the light impinging on the scintillator's readout surface from the *interior* of the crystal.

120 In CAMFR we define the side of the photonic crystal. CAMFR then calculates the behavior of this pattern 121 on the incident light using us input the internal angular light distribution produced before by Geant4 and, in this 122 way, determines how much  $\epsilon i$  the light is extracted and how much of it reflected. It is important to note that 123 CAMFR is an analytical toon the simulates a pattern without defects. It is impossible to simulate the effect of 124 non-periodic defects  $\epsilon$  in the fore estimate their relevance.

### 125 **3.2 Results**

We have sin ulated the pattern obtained from the SEM on our sample, in other words the pillars of 300 nm height and a dian, ter of 390 nm in a square lattice with 580 nm periodicity. The transmission of the 420 nm light in this p<sup>1</sup> corpic crystal slab is shown in Fig. 4. [insert figure 4 here, file "lighttransmission.tif"]

The red-sha' d area in the graph of Fig. 4 shows that the photonic nanopattern reflects a fraction of the light coming from the *in side* of the extraction cone that otherwise would have been extracted with no photonic pattern on the crystal. On the other hand, the green-shaded area in Fig. 4 denotes that part of the light that lies *outside* of the extraction cone, i.e. light that would have been reflected internally and hence lost without the photonic slab, and now being extracted because of this layer. Furthermore, light still not being extracted by the photonic crystal is understood to be internally reflected by the photonic crystal in a diffracted manner and therefore under angles different from the incident angle. As angles of the reflected light from outside of the extraction cone change, a 136 significant fraction of this light is reflected inside the extraction cone and can therefere be extracted from the 137 opposite side of the cube at the non-patterned crystal face. This provides an additional penefit in light yield when 138 one reads out the crystal from the face opposite to the patterned surface.

Simulations were run for the following cases: a cubic 10x10x10 mm<sup>3</sup> LYSO cryst 1, coupled to air, with and 139 140 without a photonic crystal slab, and also with and without Teflon wrapping as a comparison. Figures <u>5a</u> and <u>5b</u>, respectively, show their effect on light extraction. In the case where there is no vrapping (Fig. 5a), we calculate 141 142 a light gain of 1.51 due to the photonic crystal layer at first incidence. In the case, however, where the scintillator cube is wrapped with Teflon the benefit from the photonic layer is reduced esuling in a gain of only 1.25 at first 143 144 incidence. This difference is attributed to the two different internal angula, <sup>17</sup> ght distributions (due to different light reflection from the side walls and the back of the crystal) from the superate configurations studied. 145 [insert figures 5a,b here, files "lighttransmission nowrap.tif" and "light ransmission teflon.tif"] 146

Further simulations were made to understand the effect of a possible sidual TiO<sub>2</sub> layer estimated to be 148 120 nm thick, i.e. a remnant layer from a possibly incomplete etching  $r_{10}$  ess, as observed in the SEM image in 149 Fig. 3c and discussed above. The effect of a residual TiO<sub>2</sub> thickness of 1'.0 nm was simulated and is shown in 150 Table 1. In these simulations we have assumed the total thickness of the TiO<sub>2</sub> layer prior to etching to be 300 151 nm. Absorption by the residual TiO<sub>2</sub>, however, was not considered, since it is highly transparent to 420 nm light. 152 Table 1

	isinual IIO <sub>2</sub> Layer [IIII]		
	0	120	
LY Gain without Teflon:	1.51	1.59	
LY Gain with Teflon:	1.25	1.35	

From this we infer that the presence of the residual  $TiO_2$  layer does not necessarily lead to a degradation in light output; it may even have a benefic at e. cect on the light yield. Further studies are needed though to corroborate this assumption.

### 159 **4. Measurements**

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### 160 **4.1 Characterization methods**

### 4.1.1 Light yield

The light yield is measure *i i* exciting the scintillating crystal with a <sup>137</sup>Cs gamma source. The generated light is collected by a photom (tip) ier (Hamamatsu R2059) mounted, without optical coupling, to one face of the crystal. The PMT signal is digitieed, and an energy spectrum produced. The position of the photopeak is then equivalent to the number of collected photons. The ratio between light measured with an un-patterned and patterned crystal defines the can in light yield due to the introduced pattern.

### 167 *4.1.2 CTR*

168 The test bench fo. the C<sup>7</sup> R measurements consists of two scintillators facing each other in a back-to-back arrangement and bring encired by two correlated and colinear gammas (511 keV) from a <sup>22</sup>Na source. As one of 169 the crystals is us d as a tandard or reference crystal with its own intrinsic time resolution determined from an 170 171 independent CTR neasu ement prior to our test series, the time resolution of the crystals under investigation can 172 be derived fr — the acconvolution of the reference time resolution and the jointly measured CTR. Both the 173 reference cryst.<sup>1</sup> *e* id the crystal under test are coupled to a SiPM; in our case, the crystal under test is coupled to 174 the SiPM with an air gap, from where the signal is split (a) for time stamping with a high frequency amplifier 175 (~1.5 GHz bandwidth) [11] and (b) for an independent pulse height measurement with a low-noise analog 176 operational amplifier [11], geared to obtain the energy of the photoelectric peak. The signals are digitized by a LeCroy DDA 735Zi oscilloscope. After event selection constraining data to the photopeak (511 keV events), the 177 178 joint CTR is derived from the FWHM of the Gaussian fit of the correlated time stamp (time delay) histogram. In 179 order to measure the light signal from the 10x10x10 mm<sup>3</sup> LYSO:Ce cube, we used a Hamamatsu S13360 SiPM 180 with

181  $6x6 \text{ mm}^2$  size having  $50x50 \text{ }\mu\text{m}^2$  single photon avalanche diodes. This means that not the whole surface area was coupled to the SiPM and only the central light was measured, resulting in a ...terioration of the CTR. 182 183 Nevertheless, this does not compromise the validity of comparison studies.

#### 184 4.2 Results from light yield and energy resolution measurements

LY was investigated and compared for two wrapping scenarios, i.e. withen the vitil Teflon wrapping of 185 the crystals, and respectively three and two configurations each: 186

- 1. Without Teflon wrapping (three configurations): 187
- a. Non-patterned reference crystal mounted to PMT; 188
- 189 b. Patterned crystal with patterned face mounted to PMT;
- Patterned crystal with opposite face mounted to PMT. 190 C.

#### 191 2. With Teflon wrapping (two configurations):

- a. Non-patterned reference crystal mounted to PMT;
- b. Patterned crystal with patterned face mounted to PMT.
- 194 c. Measurements with the opposite face mounted to the SiPM were not performed in order not to damage the photonic pattern with the Teflon wrat ring. 195
- The results are shown in Table 2. 196

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#### 197 4.2.1 PMT measurements without Teflon wrapping

198 For the case of no wrapping, the patterned crystal improves LY and energy resolution by a factor of 1.5 and 1.1 respectively. This is in good agreement with the involutions assuming 0 nm residual  $TiO_2$  layer. It is 199 interesting to see that a nearly identical gain in light y'e.d is achieved when the crystal is read out from the 200 untreated side, opposite to the patterned surface. The indeed is also expected from the simulations as explained 201 202 in Section 3.2. The gain in energy resolution is in line with what one would expect on purely statistical grounds 203 (Equation 1), taking into account the error on the mean ment.

### 4.2.2 PMT measurements with Teflon wrapping

205 When the crystals, reference and patter ... nes, are wrapped in Teflon, the relative gain in light yield drops to 1.4. This is slightly higher than expect d from the simulations and could be an indication of the presence of 206 207 the residual TiO<sub>2</sub> layer presumed in on ot or completion schemes, in which case the light yield would match the simulations perfectly. However, if the residual layer of 120 nm indeed exists, the crystal measurements 208 209 without wrapping should also match up corresponding simulations, which is not the case. Another contribution 210 to the slightly higher measured views with Teflon wrapping could be due to a difference in how the Teflon 211 affects the directionality of the light. The simulations compared to the actual behavior. The energy resolution improves in a configuration with Teflon wrapping i.e. by a factor of 1.2, in line with photostatistics. 212

are me	asur d with a	% accuracy,	leading to an a	accuracy of 7%	for the measu	red gain.	and energy
	Gain 't' O 'm resic tal T' J <sub>2</sub>	Simulated Gain with 120 nm residual TiO <sub>2</sub>	Measured LY with PMT [Ph/MeV] (x 10 <sup>3</sup> )	Measured Energy- Resolution with PMT [%]	Measured Gain in LY with PMT	Measured Gain in Energy Resolution with PMT	Expected Gain in Energy Resolution from LY
Reference crysta without wrappin.	) -	-	4.4	19	-	-	-
PhC facing detector without wrath ping	1.5	1.6	6.5	16	1.5	1.1	1.2
PhC from opposite vide without wrapping	-	-	6.5	17	1.5	1.1	1.2

Table 2: Comparison of simulated and easured I V and en n and their improvements (gain) Both I V and energy

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Reference crystal with wrapping	-	-	13	11	- /	-	-
PhC facing detector with wrapping	1.3	1.4	19	9.4	1.4	1.2	1.2

### **4.3 Results from coincidence time resolution (CTR) measurements**

Similar to our foregoing LY measurements, the CTR was investigate and compared for five different configurations as described in Section 4.2, however, using SiPMs instead of PM.s.

Over a large threshold range, i.e. 2-115 mV, and the above configurations a series of coincidence time resolution (CTR) measurements was made using the high frequency r adout for time stamping as explained in section 4.1.2. The results of these runs are shown in Fig. 6 (scenario 1) and Fig 7 (scenario 2), where the CTR is plotted against the applied threshold. [insert figure 6 here, file "CTR\_...ap.tif"] [insert figure 7 here, file "CTR\_teflon.tif"]

From Fig. 6 (unwrapped scenario) we notice that the higher coincidence time resolution (i.e. lowest CTR value) is obtained for the photonic crystals of 390 ps FWHM with displayer patterned surface read out by the SiPM, and 375 ps when read out from the opposite crystal face (value, taken rom the fits in fig. 6). In this scenario, the reference crystal achieves a CTR of 450 ps FWHM only. This danslates into a CTR-gain of 1.2 at lowest thresholds increasing systematically towards higher threshold values is (see also Fig. 8).

On the other hand, Fig. 7 (wrapped scenario) clearly bows that wrapped scintillators, as expected [12], provide higher time resolution than non-wrapped crys do. Vot the photonic crystal still has a superior CTR than its reference counterpart, i.e. achieving 300 ps FWHM resus 317 ps FWHM (values taken from the fits in fig. 7) constituting a factor of about 1.1 improvement ac compared to the non-patterned crystal at low thresholds, and increasing steadily at higher thresholds (Fig. 9).

The measurements above also show that d = CTR is very sensitive to threshold changes, though less pronounced for the photonic crystals compared to their untreated references. The same holds for those scintillators that are wrapped in Teflon in compared to the unwrapped ones. This correlation is better visualized in Figures 8 and 9 corresponding to unwrapped and wrapped crystals, respectively, where the CTR ratio of reference and photonic crystals is shown as a function of threshold. [insert figure 8 here, file "ratioCTR\_nowrap.tif"] [insert figure 6, fil, "ratioCTR\_teflon.tif"]

In Tables 3 and 4, corresponding to the two scenarios of unwrapped und wrapped scintillators, we list some specific values for the gain in CTF at given thresholds and compare this with the CTR gain to be expected from LY measurements considering photosul stricts only, i.e. taking the square root of the light yield gain. It can be seen that the resulting CTR in  $_{4}$  vements (gain) correlate (within the statistical uncertainties) with the light yield gain for low thresholds i.e.  $-1.22 (=\sqrt{1.5})$  versus a LY gain of 1.5 in the un-wrapped case. On the other hand, for the wrapped case the correctation in CTR improvement considering pure photostatistics is higher, i.e.  $\sqrt{1.4} = 1.18$  as compared to the measured value of about 1.1.

Table 3:List of CTF measurements and their gain compared to expected values derived from LYmeasurements are made without Teflon wrapping. The values are taken from thefits in fig. 6. The CTR is measured with a 3% accuracy, leading to an accuracy of 4% for themeasured  $_{c.in}$  in  $_{c.TR}$ . Considering the error in the measured gain in LY, the expected gain in CTRfrom the measured  $_{c.in}$  in  $_{c.TR}$ . Considering the error in the measured gain in LY, the expected gain in CTRfrom the measured  $_{c.in}$  in  $_{c.TR}$ . Considering the error in the measured gain in LY, the expected gain in CTR

Crevetal face	Best measured	CTR Improvement (Gain)					
ben gread out:	CTR FWHM [ps]	@ best CTR	@ 10 mV Threshold	@ 100 mV Threshold	Expected from LY measured w/ PMT		
Reference crystal	450	-	-	-	-		
Photonic	390	1.2	1.3	1.9	1.22		
Opposite	375	1.2	1.3	2.0	1.22		

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### Table 4:

List of CTR measurements and their gain compared to expected values  $e^{-1}$  rived from LY measurements: All measurements are made with Teflon wrapping. The values are taken from the fits in fig. 7. The CTR is measured with a 3% accuracy, leading to an accuracy of 4% for the measured gain in CTR. Considering the error in the measured gain in LY, the expected gain in CTR from the measured LY as an accuracy of about 4%.

Crystal face	Best measured	CTR Improvement (Cain)					
being read out:	CTR FWHM [ps]	@ best CTR	@ 10 mV Threshold	@ 100 .nV Thres. `1d	Fxpected from LY measured w/ PMT		
Reference crystal	317	-	-	-	-		
Photonic	300	1.1	1.1	1.3	1.18		

The results demonstrate that the nanoimprinted scintillator transfers "only more efficiently than an un-treated crystal. Additionally, and in line with our findings for LY and en my resolution, it again makes no difference from which side, front face or reversed, the crystal is read out.

The improvement in CTR over that of the reference device becomes rather high when raising thresholds to >10 mV, notwithstanding its excellent values also at lower threshold. It is also worth noting that the CTR of the patterned crystal is much less sensitive to threshold changes than the reference crystal. This is important for highly integrated systems, where tradeoffs in the electron or operate the detectors at lowest thresholds possible.

The high dependence of the CTR gain on the leaving cuge threshold, i.e. low gain for low thresholds and 268 high gain for high thresholds, can be explained by the change of light transfer modes in the photonic crystal in 269 270 contrast to its non-patterned counterpart. In order to newsigate this behavior, we conducted very preliminary 271 Monte-Carlo simulations and found that, if an additional photon transfer time spread due to the presence of the 272 photonic layer is included, the modeled CTK improvement versus the leading-edge detection threshold approaches that of the measurements. The additional time smearing in the photonic crystal arises from the fact 273 274 that about 50% of the direct photons are r needed back into the crystal whereas delayed photons that normally 275 are not collected by the photodetector c: now, nder the influence of the nanopattern, reach the SiPM. This behavior can be understood by looking at Fig. 4 where larger angles for photons exiting the crystal also mean a 276 longer travel path and therefore a la ger lelav time. Additional photons extracted by the photonic crystal at 277 278 larger angles thus come at later times a. do ontribute to the signal formation at higher leading-edge thresholds 279 and therefore improve the CTR at jigher the esholds. On the other hand, the slightly reduced number of photons 280 arriving very early at the photode ecto. <sup>1</sup>owers the CTR gain at lower thresholds.

In other words, the photonic battern in this particular case transfers early arriving photons to later times, nevertheless, increasing the otal amount of photons extracted. Hence, also at earlier times the number of photons is higher than in the non-patterned crystal and therefore improves the photostatistics leading to an overall improved CTR. In this sense the photonic pattern changes the weight of the diffractive modes. Depending on the application and the scintillator geometry this behavior varies, and it is even thinkable to use this feature of photonic crystals to optimize the time structure of detected photons in special cases.

### 287 5. Summary and Discussion

We have st ccessfu 'y produced a photonic crystal slab, manufactured via nanoimprint lithography and made of  $TiO_2$  on cm of a 10x10x10 mm<sup>3</sup> LYSO:Ce cube. The produced pattern is of high quality, where the imprinted str ccms have the desired shape of pillars with fine-grained periodicity. We have simulated the produced pattern and also the effect of a possible residual  $TiO_2$  layer left over from the etching process. From these simulations we can conclude that the residual layer does not necessarily have a detrimental effect and hence decrease the gain in light yield.

The photonic crystal delivers a significant increase in light yield, both when extracted from the patterned surface or from the face opposite to it. In the case that no wrapping of the crystal is used, the total gain in light yield is 1.5 and the corresponding improvement in energy resolution 1.1, irrespective of the two adjacent exit faces, patterned or un-patterned, being read out. This gain in light yield agrees with our predictions from the

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298 simulations. The gain in energy resolution, however, is slightly lower than expected from the equivalent gain in 299 LY on arguments that only photostatistics is taken into account. This might be due in inhomogeneities in the 300 nanopattern of the photonic crystal.

Time resolution seems to particularly benefit from photonic patterning, esr. c., ly for bare (un-wrapped) 301 crystals and at higher detection thresholds. In that case, gains in CTR ranging fr. m 1.2 at low threshold to more 302 than a factor of 2 at higher thresholds have been observed. Particularly, CTP improvements at highest time 303 304 resolutions obtained near the detection threshold are well in line with our expectations from photostatistics and confirmed by the corresponding LY measurements. Still further work is need to identify and factorize all 305 influences, other than statistical ones, on the time resolution, especially for Cotr at higher thresholds. 306

In the case where the tested crystals are wrapped in Teflon tape. meth.<sup>4</sup> traditionally used to increase 307 308 their light yield, the "photonic" effect and its benefit on the time esolution become less pronounced than 309 observed with bare crystals. In terms of LY and energy resolution we h, ve ob erved an improvement of 1.4 and 1.1, respectively, owing to the photonic pattern, where the gain in energy resolution is slightly lower than 310 311 expected from pure photostatistics. The obtained gains in CTR a e, s w had expected from our simulations, 312 more moderate accordingly, i.e. 1.1 at lowest threshold and 1.3 a higher "resholds.

313 In conclusion, it is shown that photonic imprinting of scintillato, in particular with the chosen process and its resulting high-quality pattern, can significantly improve light vield, energy- and time resolution in scintillator-314 315 based detection systems. While the effect is still modest as used as wrapped scintillators are used in conjunction 316 with detectors operating at very low detection thresholds the otential of this technique is far from being 317 exhausted, hence giving new incentives for further investigations on the basis of novel and more elaborate 318 patterns and their production methods. Those effort could then include a comparison with different crystal 319 surface states, such as de-polishing or micro-structurin, of the crystal face. There is still room for improvement 320 and optimization of suitable pattern types and shap in conjunction with different types of wrapping and optical 321 coupling for the crystals.

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### 358 Figure Captions

Fig. 1: **Processing steps in nano-imprint lithography**: (1) LYSO scintillater with s bsequent layers of TiO<sub>2</sub>, aluminum, and a resist deposited on its surface. (2) A stamp independently fabricated beter what with the desired pattern imprints the pattern into the resist. (3) The pattern in the resist is transferred to the *a* animum through wet-etching. (4) The imprinted aluminum layer has the pattern of the resist and is now used as a hard misk  $f_{-1}$  to 2 dry-etching process. (5) Dry-etching of the *TiO*<sub>2</sub> transfers the Al-pattern to the TiO<sub>2</sub>. (6) The hard mask is removed and t' e TiO2 is imprinted on the LYSO crystal with its final pattern.

Fig. 2a-b: **Illustrations of the photonic crystal pattern** with pillation in a quare lattice (a). Photo of the nanoimprinted surface of the LYSO:Ce cube showing the typical iridescent difference of photonic layers (b). Note, that the photonic pattern does not extend over the entire surface of the cube

Fig. 3a-c: **SEM images:** made from top of sample with 4k n 3gm ... (ion (a); top view SEM image with 20k magnification (b); SEM image of sample tilted by 70 degrees with 20k magn. <sup>c</sup> Jation (c).

Fig. 4: **Simulation of light transmission** at the LYSO crystal-a. interface, with and without a 300 nm thick photonic crystal layer as described above. The red-shaded area main area light internally reflected by the photonic crystal, coming from the *inside* of the extraction cone that otherwise wound have exited the crystal in the case of no photonic pattern. The green-shaded area indicates extracted light from *outside* of the extraction cone, i.e. light that would have been internally reflected and thus lost without the photonic nar opattern.

Figs. 5a-b: **Simulation of light transmission** at the crystal-air interface, in the case of a  $10x10x10 \text{ mm}^3$  LYSO cube equipped with and without a photonic later for the two cases that the scintillator is unwrapped (left) and wrapped with Teflon (right). For both cases, the crystal is of upler via air at the photodetector interface.

Fig. 6: **Coincidence Time Resolution** betained from a nanoimprinted LYSO cube without Teflon wrapping or optical coupling mounted on a SiPM, compared to a reference or un-patterned crystal: two crystal orientations w.r.t. the SiPM window were used: patterned-face to-, iPM (red squares), and opposite-face-to-SiPM (blue triangles). The CTR is measured with a 3% accuracy. Data for the reference crystal are shown as yellow dots. For all three configurations, the first data point at a threshold of 2 mV is in the electremic noise floor of the readout and thus leads to very high CTR values (not shown in the plot).

Fig. 7: Coincidence Time k. Au on values of a nanoimprinted LYSO cube with Teflon wrapping (but no optical coupling) compared to reference, un-patterned LYSO cube. The CTR is measured with a 3% accuracy. Measurements were made with a SiPN, and high frequency readout. For both crystals, the first data point at a threshold of 2 mV is in the noise floor of the electron. The content of the electron.

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Fig. 8: **Ratio of the CTRs** *i* otained for the patterned and un-patterned crystal without Teflon wrapping at the same detector threshold. The CTR is measured with a 3% accuracy, leading to an accuracy of 4% for the measured ratio. This demonstrates that a rywnere, other than near the noise threshold, the photonic crystal has superior performance, when it effectively improves CTR by more than a factor of two at highest thresholds.

Fig. 9: **Ratio of the CTRs** obtained for the patterned crystal with Teflon-wrapping (in only one mounting position) and the reference crystal. The CTR is measured with a 3% accuracy, leading to an accuracy of 4% for the measured ratio. Data are taken without optical coupling at thresholds of  $\geq 2$  mV to avoid noise saturation.